EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2686	(first near (tft or (thin near film near transistor))) and (second near (tft or (thin near film near transistor)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/05 17:57
L2	62	(first near (tft or (thin near film near transistor))) same polysilicon same (second near (tft or (thin near film near transistor)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/05 17:58
L3	0	(first near (tft or (thin near film near transistor))) same polysilicon same grain same (second near (tft or (thin near film near transistor)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/05 17:59
L4	6	(first near (tft or (thin near film near transistor))) same polysilicon same (crystal or grain) same (second near (tft or (thin near film near transistor)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/05 17:59